

8th CIES Technology Forum VIRTUAL

March 27 (Mon) – 28 (Tue), 2023

International Symposium

Part 1 [Live] 9:00-12:10 (JST)

March DAY2 28 (Tue) DAY2

http://www.cies.tohoku.ac.jp/8th_forum/

| JST | PDT | CET | | | | |
|--------------------------------------|-------------------------|-----------|---|---|--|--|
| 9:00-9:05 | March 27 17:00-17:05 | 1:00-1:05 | Opening remarks | Tetsuo Endoh (Tohoku Univ.) | | |
| 9:05-9:35 | 17:05-17:35 | 1:05-1:35 | Invited talk 1 | Tae Young Lee (Samsung Electronics) | | |
| | | | Status and Outlook of eMRAM Technology | | | |
| 9:35-10:05 | 17:35-18:05 | 1:35-2:05 | Invited talk 2 | Chi-Feng Pai (TSMC) | | |
| | | | Material Development toward Low Power SOT-MRAM | | | |
| 10:05-10:35 | 18:05-18:35 | 2:05-2:35 | Invited talk 3 | Sooman Seo (SK Hynix) | | |
| | | | First Demonstration of Full Integration and Characterization | | | |
| | | | of 4F ² 1S1M Cells with 45 nm of Pitch and 20 nm of MTJ Size | | | |
| 10:35-11:05 | 18:35-19:05 | 2:35-3:05 | Invited talk 4 | Hiroaki Honjo (Tohoku Univ.) | | |
| | | | iPMA-type Hexa-MTJ for High Density eFlash-type MRAM | | | |
| 11:05-11:35 | 19:05-19:35 | 3:05-3:35 | Invited talk 5 | Alex Lidow (Efficient Power Conversion) | | |
| | | | GaN IC Roadmaps | | | |
| 11:35-12:05 | 19:35-20:05 | 3:35-4:05 | Invited talk 6 | Yoshikazu Takahashi (Tohoku Univ.) | | |
| | | | Progress in Power Electronics Integration Technology | | | |
| 12:05-12:10 | 20:05-20:10 | 4:05-4:10 | Closing remarks | Tetsuo Endoh (Tohoku Univ.) | | |
| Part 2 [Streaming] 17:00-20:10 (JST) | | | | | | |
| JST | PDT | CET | | | | |
| 17:00-17:05 | 1:00-1:05 | 9:00-9:05 | Opening remarks | Tetsuo Endoh (Tohoku Univ.) | | |
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| 17:05-17:35 | 1:05-1:35 | 9:05-9:35 | | | |
|-------------|-----------|-------------|---|---|--|
| 17.05-17.55 | 1.05-1.55 | 9.05-9.55 | Status and Outlook of eMRAM Technology | | |
| 17.25 10.05 | 1:35-2:05 | 9:35-10:05 | Invited talk 2 | Chi-Feng Pai (TSMC) | |
| 17:35-18:05 | | | Material Development toward Low Power SOT-MRAM | | |
| | | | Invited talk 3 | Sooman Seo (SK Hynix) | |
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| 10.25 20.05 | 3:35-4:05 | 11.35-12.05 | Invited talk 6 | Yoshikazu Takahashi (Tohoku Univ.) | |
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| 20:05-20:10 | 4:05-4:10 | 12:05-12:10 | Closing remarks | Tetsuo Endoh (Tohoku Univ.) | |
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Organizer:Center for Innovative Integrated Electronic Systems (CIES), Tohoku Univ.Co-sponsored:Research Institute of Electrical Communication (RIEC), Tohoku Univ.Sponsors:CAO, MEXT, METI, JPO, JSPS, JST, NEDO, INPIT